Electronic Structure and Transition Intensities in Rare-Earth Materials



ENERGY LEVELS OF THE +3 LANTHANIDES IN LaF,



Fig. 23. Energy Level Structure of Ln³⁺:LaF₃ Based on Computed Crystal-field Energies in the Range 0-50000 cm⁻¹.



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Outline

- Background on rare-earth (lanthanide) ions.
- States and transitions
- Effective Hamiltonian for 4f^N
- Some simple calculations of energy levels
- Transition intensities
- 4f^{N-1}5d
- Ab-initio calculations



Gerhard Dieke Johns Hopkins 1950-1965





1960's Theory: Judd, Ofelt, Wybourne



Filling of orbitals









Lanthanide 3+ ground state: 5s² 5p⁶ 4f^N 5d⁰



Lanthanides: 4f^N, 4f^{N-1}5d, Excitons

• 4f^N

- Sharp lines
- Long lifetimes
- So ideal for laser and phosphor applications



■ 4f^{N-1}5d

- Broad absorption bands from 4f^N
- Useful for absorbing energy
- Short lifetimes useful in some applications, such as scintillators

Excitons

- Excited electron can become delocalized, giving an excitonic state.
- Charge Transfer Transitions
 - Ligand to lanthanide electron transfer





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Transitions

- 4f^N 4f^N
 - No configuration shift
 - Sharp lines
- $4f^N 4f^N 5d$
 - Configuration shift
 - Broad bands
- Excitonic states $\rightarrow 4f^N$
 - Large configuration shift
 - Very broad bands





How do we proceed?

- Ab-initio (first principles) calculations
 - Well established in atoms
 - Hartree-Fock + perturbations
 - Now viable for lanthanide complexes but slow
- Effective Hamiltonians ("crystal field")
 - Requires parameter fitting
 - Relatively quick and easy, allowing rapid interpretation of spectra.
 - Can be related to ab-initio calculations.

Effective Hamiltonian Calculations

- H $|\Psi_i\rangle = E_i |\Psi_i\rangle$ (H is Hamiltonian)
- $H_{eff} | \phi_i \rangle = E_i | \phi_i \rangle$ (H_{eff} is Effective Hamiltonian) $E_{Theory} E_{Expt}$ $(H) \rightarrow (H_{eff})$ $(H_{eff}) \rightarrow \sum_{\alpha} P_{\alpha}(M_{\alpha})$



All increase energy of z orbital more than x,y Orbital energies \leftrightarrow crystal-field parameters₃



Effective Hamiltonian for 4f^N



Correlation and other corrections

$$+\alpha L(L+1) + \beta G(G_2) + \gamma G(R_7) + \sum_{i=2,3,4,6,7,8} T^i t_i$$

+
$$\sum_{h=0,2,4} M^h m_h + \sum_{k=2,4,6} P^k p_k$$



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Calulating Matrix elements

Wigner-Eckart Theorem

$$\langle \alpha JM | T_q^{(k)} | \alpha' J'M' \rangle = (-1)^{J-M} \begin{pmatrix} J & k & J' \\ -M & q & M' \end{pmatrix} \langle \alpha J | | T^{(k)} | | \alpha' J' \rangle$$

matrix element "geometrical" factors

"reduced" matrix element

- Selection Rules
 - M'+q = M
 - J k J' form a triangle: $|J-J'| \le k \le J+J'$
- SLJM> states
 - More complex versions of WET.
 - Triangle rules for S S' L L' J J' and operator labels.

Ce³⁺: 4f¹ 5d¹



Free-ion splitting is 2253 cm⁻¹ so ζ = 644 cm⁻¹

Similarly for 5d¹

Splitting of J=5/2 multiplet Magnetic field M = +5/2- Even spacing: M = +3/2M = +1/2 0.4 cm⁻¹ for 1T field M = -1/2M = -3/2M = -5/2 Crystal Field $H_{\rm cf} = \sum B_q^k C_q^{(k)}$ M=±1/2 E=258 J = 5/2M=±3/2 E=172 Uneven spacing - Example: $M = \pm 5/2 E = 0$ • $B_0^2 = 500 \text{ cm}^{-1}$ – More complex cases mix up M labels. 19

Superposition Model

$$B_q^k = \sum_L \bar{B}_k(R_0)(-1)^q C_{-q}^{(k)}(\theta_L, \phi_L) \left(\frac{R_0}{R_L}\right)^{t_k}$$

$$C_0^{(2)}(x,y,z) = \frac{1}{r^2}\sqrt{\frac{1}{4}}(3z^2 - r^2)$$





Pr³⁺ : 4f² Coulomb + Spin-orbit

$$E({}^{3}H_{J}) = -0.0906F^{2} - 0.0328F^{4} + 0.0162F^{6} = -7359 \text{ cm}^{-1},$$

$$E({}^{3}F_{J}) = -0.0239F^{2} - 0.0163F^{4} - 0.0209F^{6} = -3155 \text{ cm}^{-1},$$

$$E({}^{1}G) = -0.01128F^{2} + 0.1221F^{4} + 0.0205F^{6} = -1644 \text{ cm}^{-1},$$

 $E({}^{1}G_{4}) = -0.1128F^{2} + 0.1031F^{4} + 0.0285F^{6} = -1641 \text{ cm}^{-1}.$



Tm³⁺: 4f¹²

Spin-orbit much larger and matrix elements change sign.





Transition Intensities

- Electric Dipole, Magnetic Dipole, ...
- ED between 4f^N and 4f^{N-1}5d can be calculated directly
 - But require modelling of vibronic bands.
- ED within 4f^N are parity forbidden.
 - Construct Effective ED operator that accounts for mixing of configurations of opposite parity on ion or ligand.
 - First detailed treatment: Judd, Ofelt, 1962.

Effective Electric Dipole Operator

$$D_{\text{eff},q} = D_q^{(1)} + D_q^{(1)} \sum_{\beta \notin \mathcal{M}} \frac{|\beta\rangle \langle \beta| V}{E_0 - E_\beta^{(0)}} + \sum_{\beta \notin \mathcal{M}} \frac{V|\beta\rangle \langle \beta|}{E_0 - E_\beta^{(0)}} D_q^{(1)} + \dots$$

Can derive a parametrization. $\lambda=2,4,6, t=\lambda\pm1, \lambda$ $D_{\text{eff},q} = \sum_{\lambda,t,p} A_{tp}^{\lambda} U_{p+q}^{(\lambda)} (-1)^q \langle \lambda(p+q), 1-q|tp \rangle$

Dipole strength

$$S_{FI,q}^{\text{ED}} = \sum_{i} \sum_{f} e^{2} \left| \langle Ff | D_{q}^{(1)} | Ii \rangle \right|^{2}$$

Oscillator strength

Einstein A coefficients $(1/\tau)$

$$f_{FI,q}^{\rm ED} = \frac{2m\omega}{\hbar e^2} \frac{\chi_{\rm L}}{n} \frac{1}{g_I} S_{FI,q}^{\rm ED}$$

$$A_{FI,q}^{\rm ED} = \frac{1}{4\pi\epsilon_0} \frac{4\omega^3}{\hbar c^3} n\chi_{\rm L} \frac{1}{g_I} S_{FI,q}^{\rm ED}$$



Multiplet-Multiplet transitions

- Judd 1962
 - For solutions and glasses at room temperature.
 - Sum over all states in a multiplet and all polarizations.
 - Reduces to three-parameter *linear* fit.
 - Ω_{λ} parameters with λ =2,4,6
 - Over 3000 citations!

$$\bar{S}_{\alpha_F J_F, \alpha_I J_I}^{\text{ED}} = \frac{1}{3} e^2 \sum_{\lambda} \Omega_\lambda \langle \alpha_F J_F \| \mathbf{U}^{(\lambda)} \| \alpha_I J_I \rangle^2$$
$$\Omega_\lambda = \sum_{t, p} \frac{1}{2\lambda + 1} \left| A_{tp}^\lambda \right|^2$$



Eu³⁺: ${}^{5}D_{0} \rightarrow {}^{7}F_{J}$ Emission



Eliminate options: Pr-Yb downconversion

Linda Aarts , Spectroscopy Letters, 43:373-381, 2010



TABLE 1 Reduced Matrix Elements $(U^{(t)})^2$ for Transition Starting from the $Pr^{3+1}G_4$ Level

Transition	$(U^{(2)})^2$	$(U^{(4)})^2$	(<i>U</i> ⁽⁶⁾) ²
$\overline{{}^1G_4 \rightarrow {}^3H_4}$	0.00141	0.00635	0.02206
${}^{1}G_{4} \rightarrow {}^{3}H_{5}$	0.03739	0.09615	0.41314
$^{1}G_{4} \rightarrow {}^{3}H_{6}$	0.25226	0.25337	0.23683
$1_{G_4} \rightarrow \frac{3}{F_2}$	0.00004	0.01580	0.00587
${}^1G_4 \rightarrow {}^3F_3$	0.00381	0.00531	0.05173
${}^1G_4 \rightarrow {}^3F_4$	0.07819	0.14271	0.34419
Sum	0.37310	0.51968	1.07382
Percentage $({}^1G_4 \rightarrow {}^3H_4)$	0.38	1.2	2.1

The percentages in the bottom row give the $(U^{(t)})^2$ strength for the ${}^{1}G_4 \rightarrow {}^{3}H_4$ transitions relative to the sum of all $(U^{(t)})^2$ values for a given value of *t*.

 ${}^{1}G_{4} \rightarrow {}^{3}H_{4}$ can never be strong...



Understanding the energy levels: 4f^{N-1}5d



40 x 4f (20,000 vs 500)

Conduction Band, Free Electrons, Excitons





CaF₂ (cubic sites)

 $Ce^{3+}: 4f^1 \rightarrow 5d^1$

$Pr^{3+}: 4f^2 \rightarrow 4f^15d^1$

$Nd^{3+}: 4f^3 \rightarrow 4f^25d^1$

First-Principles Calculations

- Relativistic ab-initio calculations are now possible for these systems.
- Ogasawara et al.
 J. Solid State Chem. 178, 412 (2005).
 - Calculations for entire series. Some inaccuracies.
- Seijo et al.

J. Chem. Phys. 125, 074511 (2006)

 Very accurate and detailed calculations for particular ions, including potential surfaces.





SrCl₂:Yb²⁺

Sánchez-Sanz et al. J. Chem. Phys. 133, 114509 2010

Some of our recent work is on extracting parameters from these calculations.



Conclusion

- Effective Hamiltonian for 4f^N
- Examples of energy level calculations
- Transition intensities
- 4f^{N-1}5d
- Ab-initio calculations
- Further information and *exercises*:

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